NSN 5962-01-468-5930

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.1 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and monolithic and programmable and ultraviolet erasable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Product Name:
Microcircuit, memory, digital, cmos uv erasable programmable logic array, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Memory Device Type:
Eprom
Special Features:
Generic p/n 7c335, circuit function-12 macrocell epld, fmax3-83 mhz, data retention-10 years, endurance-25 erase/write cycles
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0